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Sheet 1 of 1

Form 1449\*

Atty. Dock 1977 222US1 Serial No. 09/382,442

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(Use several sheets if necessary)

Applicant: Alan R. Reinberg

Filing Date: August 25, 1999

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		Yana	Class	Subclass	Filing Date If Appropriate
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